TOSHIBA DIODE Silicon Epitaxial Planar Type

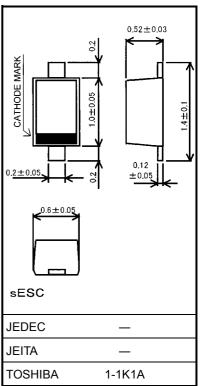
# JDV2S10S

# VCO for UHF Band Radio

- High Capacitance Ratio:  $C_{0.5V}/C_{2.5V} = 2.5$  (typ.)
- Low Series Resistance  $: r_s = 0.35 \Omega$  (typ.)
- This device is suitable for use in a small-size tuner.

#### Maximum Ratings (Ta = 25°C)

| Characteristics           | Symbol           | Rating  | Unit |
|---------------------------|------------------|---------|------|
| Reverse voltage           | V <sub>R</sub>   | 10      | V    |
| Junction temperature      | Tj               | 150     | °C   |
| Storage temperature range | T <sub>stg</sub> | -55~150 | °C   |



Weight: 0.0011 g (typ.)

# **Electrical Characteristics (Ta = 25°C)**

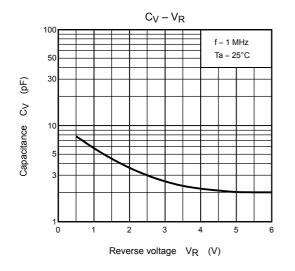
| Characteristics   | Symbol                               | Test Condition                    | Min  | Тур. | Max | Unit |
|-------------------|--------------------------------------|-----------------------------------|------|------|-----|------|
| Reverse voltage   | V <sub>R</sub>                       | $I_R = 1 \ \mu A$                 | 10   | _    | _   | V    |
| Reverse current   | I <sub>R</sub>                       | V <sub>R</sub> = 10 V             |      | _    | 3   | nA   |
| Capacitance -     | C <sub>0.5V</sub>                    | $V_{R} = 0.5 V, f = 1 MHz$        | 7.3  | _    | 8.4 | рF   |
|                   | C <sub>2.5V</sub>                    | $V_R = 2.5 V, f = 1 MHz$          | 2.75 | _    | 3.4 |      |
| Capacitance ratio | C <sub>0.5V</sub> /C <sub>2.5V</sub> | —                                 | 2.4  | 2.5  | _   | —    |
| Series resistance | r <sub>s</sub>                       | V <sub>R</sub> = 1 V, f = 470 MHz |      | 0.35 | 0.5 | Ω    |

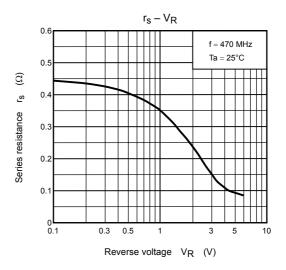
Note: Signal level when capacitance is measured:  $V_{sig} = 500 \text{ mVrms}$ 

## Marking



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